

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Hiroyuki Okuyama, et al.
Appl. No.: 10/062,687
Filed: January 30, 2002
Title: SEMICONDUCTOR LIGHT-EMITTING DEVICE AND PROCESS FOR
PRODUCING THE SAME
Art Unit: Unknown
Examiner: Unknown
Docket No.: 113278-005

Assistant Commissioner for Patents
Washington, DC 20231

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 37 C.F.R. 1.97, and 37 C.F.R. 1.98, Applicants request that a citation and examination of the references cited below, and on the attached PTO-1449 form, copies of which are enclosed, be made during the course of examination of the above-identified application for United States patent.

U.S. PATENT DOCUMENTS

<u>Document No.</u>	<u>Date</u>	<u>Inventor</u>
5,981,977	November 9, 1999	Furukawa et al.

FOREIGN PATENT DOCUMENTS

<u>Document No.</u>	<u>Date</u>	<u>Country</u>
08-255929 ✓	October 1, 1996	Japan
09-199419 ✓	July 31, 1997	Japan
10-265297 ✓	October 6, 1998	Japan
10-270801 ✓	October 9, 1998	Japan
10-312971 ✓	November 24, 1998	Japan
10-321910 ✓	December 4, 1998	Japan
11-238687 ✓	August 31, 1999	Japan
11-274568 ✓	October 8, 1999	Japan
2000-012976 ✓	January 14, 2000	Japan
2000-150391 ✓	May 30, 2000	Japan

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OTHER DOCUMENTS

J. Wang et al., *Fabrication of nanoscale structures of InGaN by MOCVD lateral overgrowth*, Journal of Crystal Growth 197 (1999), pp. 48-53.

Raj Singh et al., *Selective Area Growth of GaN Directly on (0001) Sapphire by the HVPE Technique*, MRS Internet Journal Nitride Semiconductor Research, 3, 13 (1998), pp. 1-4.

Zhigang Mao, et al., *Defects in GaN Pyramids Grown on Si(111) Substrates by Selective Lateral Overgrowth*, pp. 1-6; Materials Research Society Meeting in Boston, Mass. (1998).

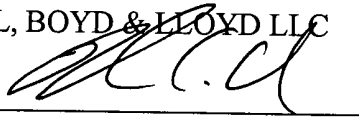
Applicants are also submitting herewith a copy of an English language Abstract for the Japanese Patent Documents submitted with the IDS filed on March 14, 2002.

Applicants look forward to early and favorable consideration of this matter.

Respectfully submitted,

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BY


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